

ES2ABF THRU ES2JBF

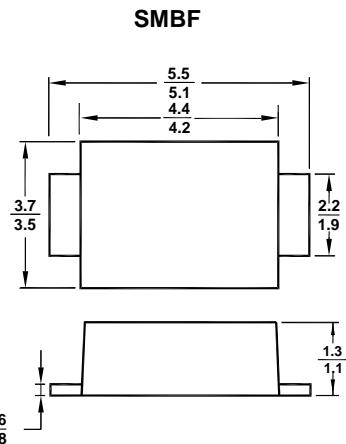
Surface Mount Superfast Recovery Rectifier
Reverse Voltage - 50 to 600 V
Forward Current - 2 A

Features

- Glass Passivated Chip Junction
- For surface mounted applications
- Low profile package
- Superfast reverse recovery time

Mechanical Data

- **Case:** SMBF
- **Terminals:** Solderable per
MIL-STD-750, Method 2026



All Dimensions in mm

Absolute Maximum Ratings and Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20%.

Parameter	Symbols	ES2ABF	ES2BBF	ES2CBF	ES2DBF	ES2EBF	ES2GBF	ES2JBF	Units			
	Marking	E2AB	E2BB	E2CB	E2DB	E2EB	E2GB	E2JB	-			
Maximum Repetitive Peak Reverse Voltage	V _{RRM}	50	100	150	200	300	400	600	V			
Maximum RMS Voltage	V _{RMS}	35	70	105	140	210	280	420	V			
Maximum DC Blocking Voltage	V _{DC}	50	100	150	200	300	400	600	V			
Maximum Average Forward Rectified Current at T _a = 100°C	I _{F(AV)}	2						A				
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load (JEDEC Method)	I _{FSM}	50						A				
Maximum Forward Voltage at 2 A	V _F	1			1.25		1.65	V				
Maximum Reverse Current at Rated DC Blocking Voltage	I _R	T _a = 25°C	5			T _a = 125°C	100			µA		
Typical Junction Capacitance at V _R = 4 V, f = 1 MHz	C _j	45						pF				
Maximum Reverse Recovery Time at I _F = 0.5 A, I _R = 1 A, I _{rr} = 0.25 A	t _{rr}	35						ns				
Typical Thermal Resistance ¹⁾	R _{θJA}	65						°C/W				
Operating Junction and Storage Temperature Range	T _j , T _{stg}	- 55 to + 150						°C				

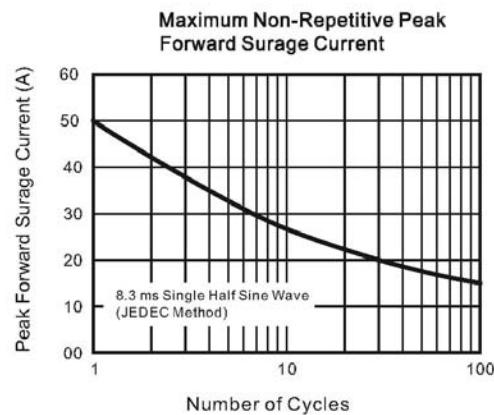
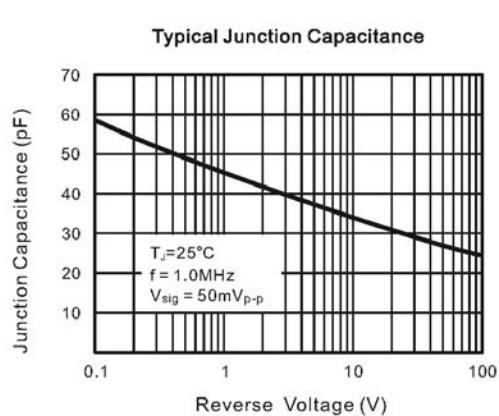
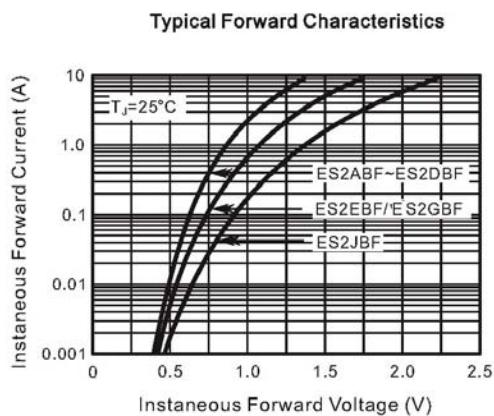
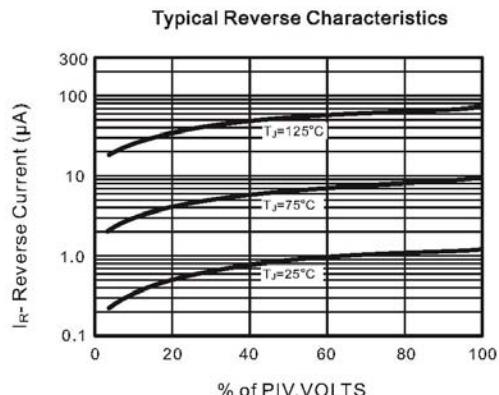
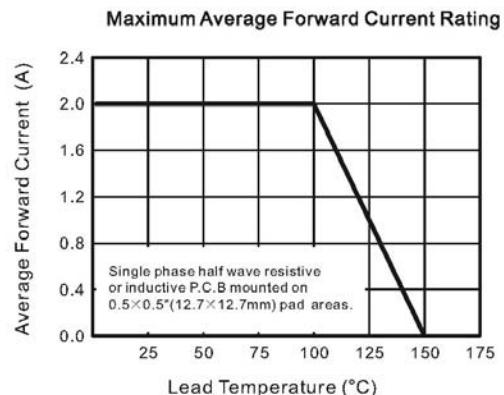
¹⁾ P.C.B. mounted with 0.5 X 0.5" (12.7 X 12.7 mm) copper pad areas.

TOP DYNAMIC



Dated: 02/03/2015 JD Rev: 01

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